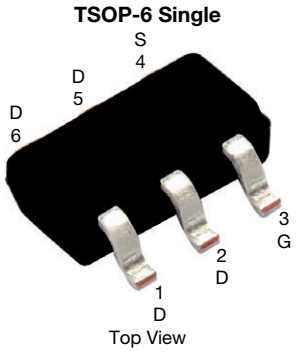
P-Channel 30 V (D-S) MOSFET



Marking code: AT

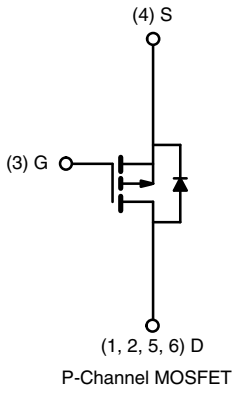
FEATURES

- TrenchFET® power MOSFET
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

Pb-free
RoHS COMPLIANT
HALOGEN FREE Available

APPLICATIONS

- Load switch



PRODUCT SUMMARY	
V_{DS} (V)	-30
$R_{DS(on)}$ max. (Ω) at V_{GS} = -10 V	0.074
$R_{DS(on)}$ max. (Ω) at V_{GS} = -4.5 V	0.113
Q_g typ. (nC)	5.1
I_D (A) [a]	-5.1
Configuration	Single

ORDERING INFORMATION	
Package	TSOP-6
Lead (Pb)-free	Si3457CDV-T1-E3
Lead (Pb)-free and halogen-free	Si3457CDV-T1-GE3

ABSOLUTE MAXIMUM RATINGS (T_A = 25 °C, unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNIT
Drain-source voltage		V_{DS}	-30	V
Gate-source voltage		V_{GS}	± 20	
Continuous drain current (T_J = 150 °C)	T_C = 25 °C	I_D	-5.1	A
	T_C = 70 °C		-4.1	
	T_A = 25 °C		-4.1 [b, c]	
	T_A = 70 °C		-3.3 [b, c]	
Pulsed drain current		I_{DM}	-20	
Continuous source-drain diode current	T_C = 25 °C	I_S	-2.5	
	T_A = 25 °C		-1.67 [b, c]	
Maximum power dissipation	T_C = 25 °C	P_D	3	W
	T_C = 70 °C		2	
	T_A = 25 °C		2 [b, c]	
	T_A = 70 °C		1.3 [b, c]	
Operating junction and storage temperature range		T_J, T_{stg}	-55 to +150	°C

THERMAL RESISTANCE RATINGS

PARAMETER		SYMBOL	TYPICAL	MAXIMUM	UNIT
Maximum junction-to-ambient [b, d]	t ≤ 5 s	R_{thJA}	55	62.5	°C/W
Maximum junction-to-foot (drain)	Steady state	R_{thJF}	34	41	

Notes

a. Based on T_C = 25 °C
b. Surface mounted on 1" x 1" FR4 board
c. t = 5 s
d. Maximum under steady state conditions is 110 °C/W

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SPECIFICATIONS (T_J = 25 °C, unless otherwise noted)						
PARAMETER	**SYMBOL**	**TEST CONDITIONS**	**MIN.**	**TYP.**	**MAX.**	**UNIT**
Static						
Drain-source breakdown voltage	V_{DS}	V_{GS} = 0 V, I_D = -250 µA	-30	-	-	V
V_{DS} temperature coefficient	$\Delta V_{DS}/T_J$	I_D = -250 µA	-	-31	-	mV/°C
$V_{GS(th)}$ temperature coefficient	$\Delta V_{GS(th)}/T_J$		-	4.5	-	
Gate-source threshold voltage	$V_{GS(th)}$	V_{DS} = V_{GS}, I_D = -250 µA	-1	-	-3	V
Gate-source leakage	I_{GSS}	V_{DS} = 0 V, V_{GS} = ± 20 V	-	-	± 100	nA
Zero gate voltage drain current	I_{DSS}	V_{DS} = -30 V, V_{GS} = 0 V	-	-	-1	µA
		V_{DS} = -30 V, V_{GS} = 0 V, T_J = 55 °C	-	-	-10	
On-state drain current [a]	$I_{D(on)}$	$V_{DS} \leq$ -5 V, V_{GS} = -10 V	-20	-	-	A
Drain-source on-state resistance [a]	$R_{DS(on)}$	V_{GS} = -10 V, I_D = -4.1 A	-	0.060	0.074	Ω
		V_{GS} = -4.5 V, I_D = -1 A	-	0.092	0.113	
Forward transconductance [a]	g_{fs}	V_{DS} = -15 V, I_D = -4.1 A	-	8	-	S
Dynamic [b]						
Input capacitance	C_{iss}	V_{DS} = -15 V, V_{GS} = 0 V, f = 1 MHz	-	450	-	pF
Output capacitance	C_{oss}		-	80	-	
Reverse transfer capacitance	C_{rss}		-	63	-	
Total gate charge	Q_g	V_{DS} = -15 V, V_{GS} = -10 V, I_D = -4.1 A	-	10	15	nC
		V_{DS} = -15 V, V_{GS} = -4.5 V, I_D = -4.1 A	-	5.1	8	
Gate-source charge	Q_{gs}		-	1.8	-	
Gate-drain charge	Q_{gd}		-	2.5	-	
Gate resistance	R_g	f = 1 MHz	-	7	-	Ω
Turn-on delay time	$t_{d(on)}$	V_{DD} = -15 V, R_L = 4.6 Ω $I_D \cong$ -3.3 A, V_{GEN} = -4.5 V, R_g = 1 Ω	-	40	60	ns
Rise time	t_r		-	80	120	
Turn-off delay time	$t_{d(off)}$		-	20	30	
Fall time	t_f		-	12	20	
Turn-on delay time	$t_{d(on)}$	V_{DD} = -15 V, R_L = 4.6 Ω $I_D \cong$ -3.3 A, V_{GEN} = -10 V, R_g = 1 Ω	-	5	10	
Rise time	t_r		-	13	20	
Turn-off delay time	$t_{d(off)}$		-	20	30	
Fall time	t_f		-	10	15	
Drain-Source Body Diode Characteristics						
Continuous source-drain diode current	I_S	T_C = 25 °C	-	-	-2.5	A
Pulse diode forward current [a]	I_{SM}		-	-	-20	
Body diode voltage	V_{SD}	I_S = -3.3 A	-	-0.8	-1.2	V
Body diode reverse recovery time	t_{rr}	I_F = -3.3 A, di/dt = 100 A/µs, T_J = 25 °C	-	20	30	ns
Body diode reverse recovery charge	Q_{rr}		-	20	30	nC
Reverse recovery fall time	t_a		-	14	-	ns
Reverse recovery rise time	t_b		-	6	-	

Notes

a. Pulse test; pulse width ≤ 300 µs, duty cycle ≤ 2 %

b. Guaranteed by design, not subject to production testing

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

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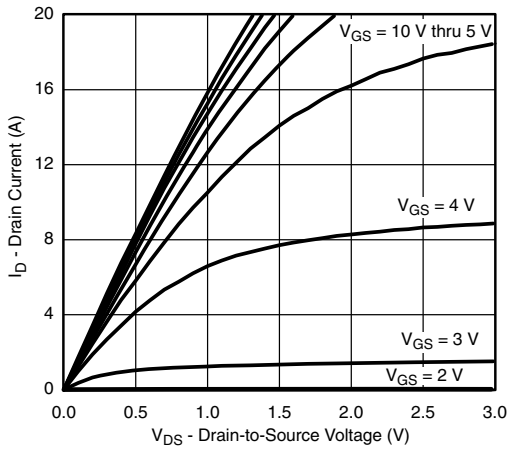
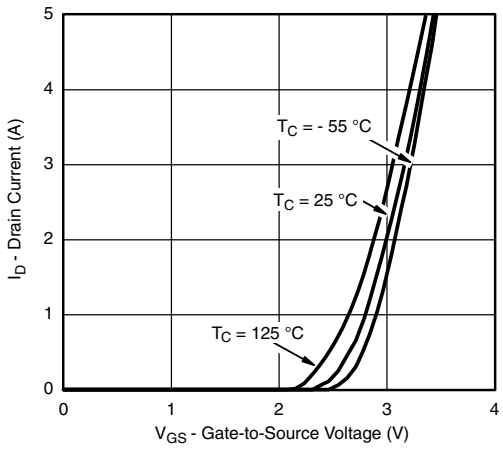
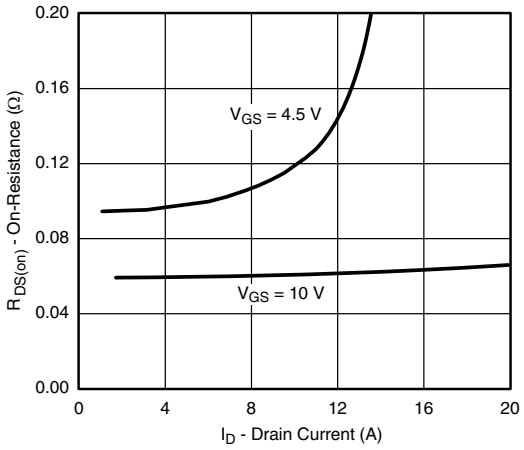
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



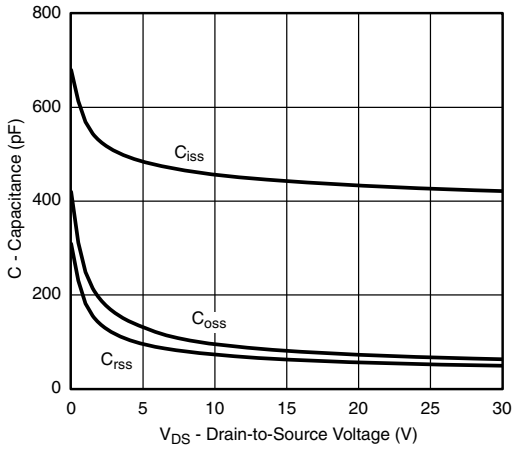
Output Characteristics



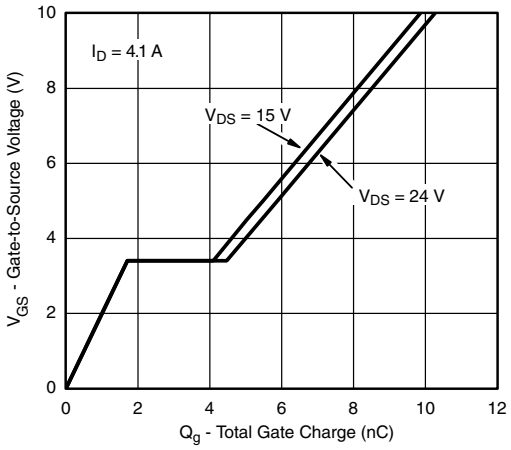
Transfer Characteristics



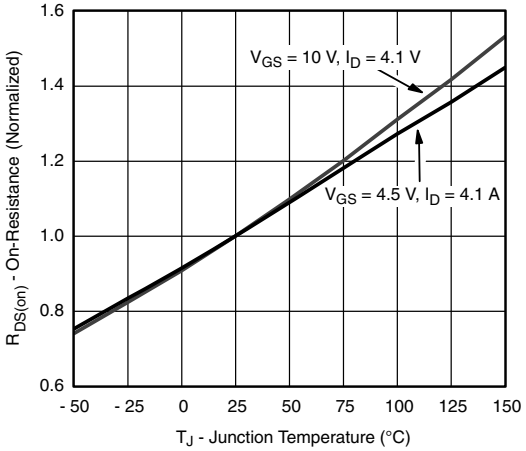
On-Resistance vs. Drain Current and Gate Voltage



Capacitance



Gate Charge



On-Resistance vs. Junction Temperature

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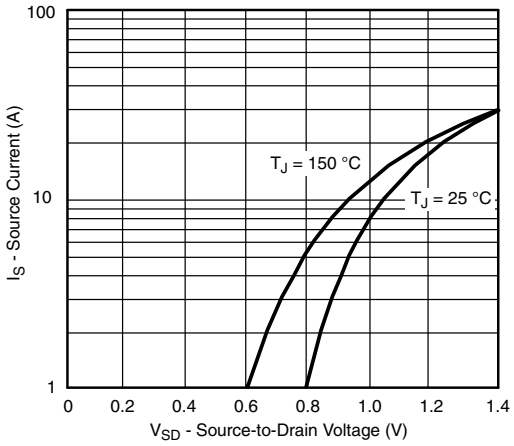
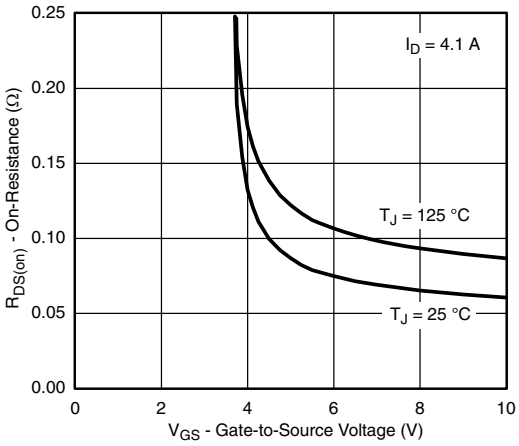
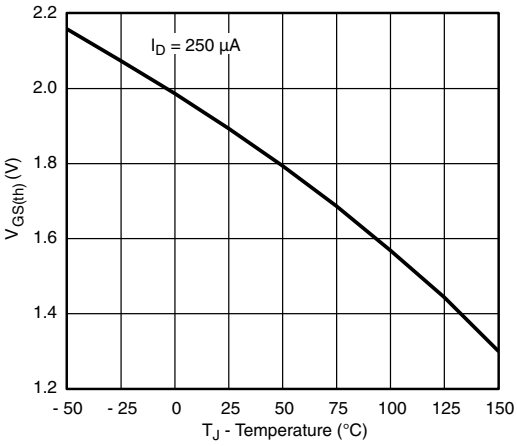


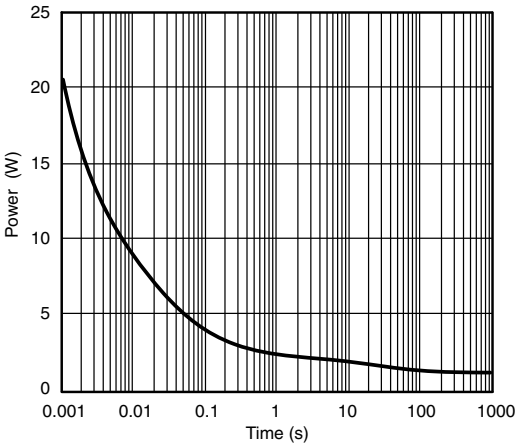
Source-Drain Diode Forward Voltage



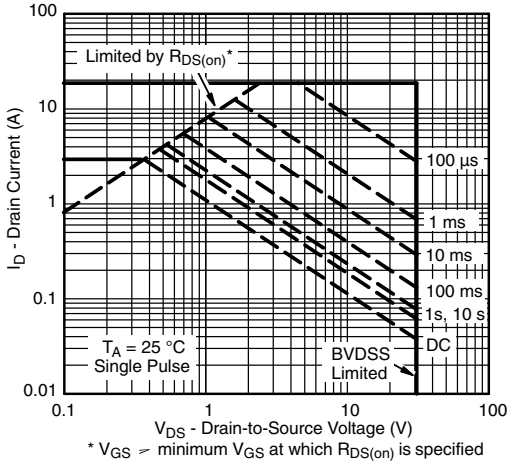
On-Resistance vs. Gate-to-Source Voltage



Threshold Voltage



Single Pulse Power



Safe Operating Area

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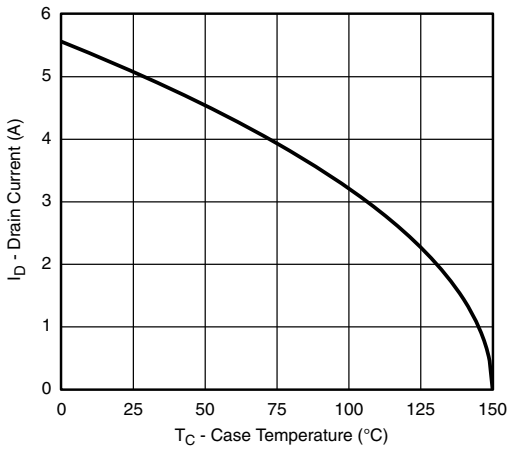
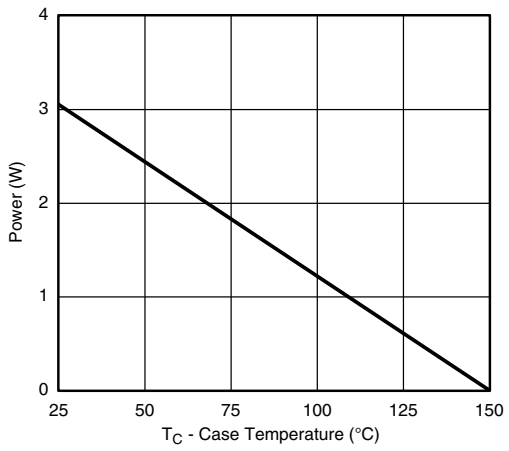


Current Derating [a]



Power, Junction-to-Foot

Notes

a. The power dissipation P_D is based on T_J max. = 150 °C, using junction-to-case thermal resistance, and is more useful in settling the upper dissipation limit for cases where additional heatsinking is used. It is used to determine the current rating, when this rating falls below the package limit

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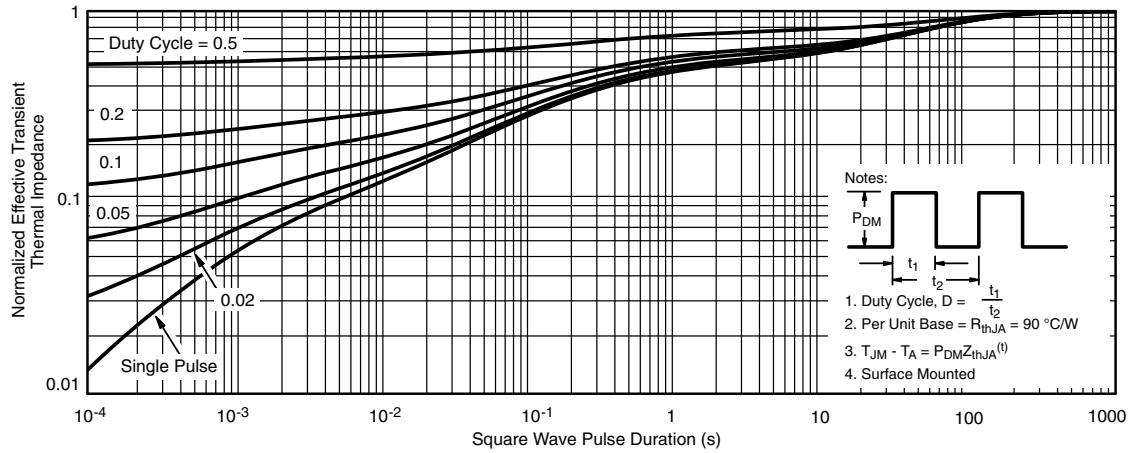
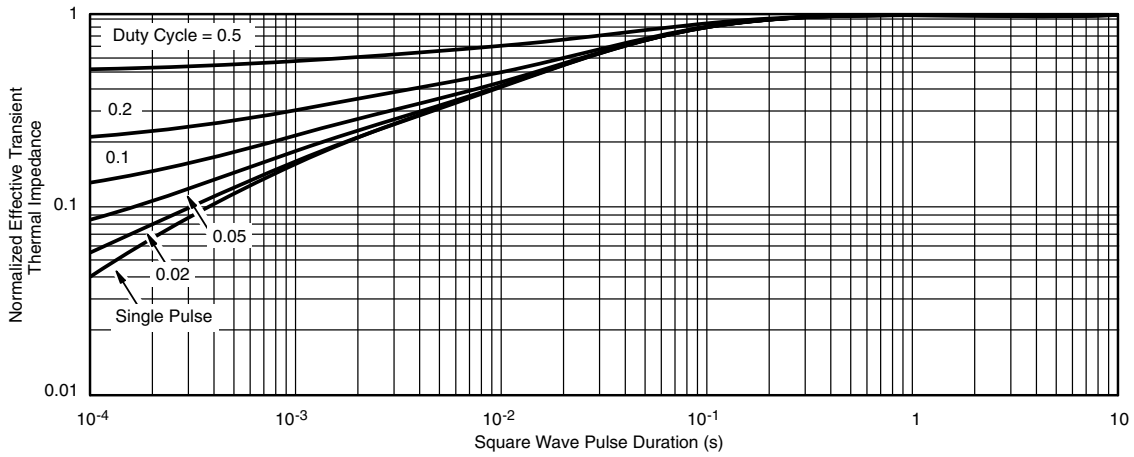


Normalized Thermal Transient Impedance, Junction-to-Ambient



Normalized Thermal Transient Impedance, Junction-to-Foot

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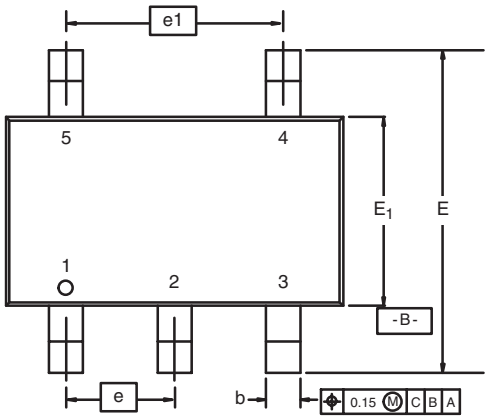
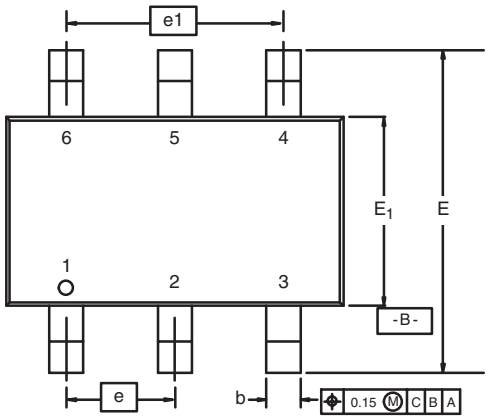
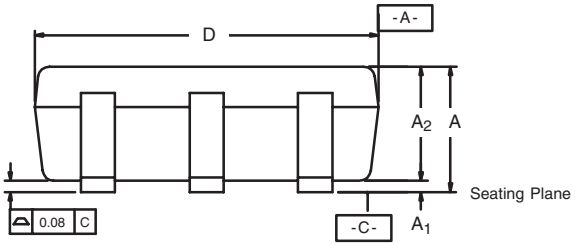
TSOP: 5/6–LEAD
JEDEC Part Number: MO-193C

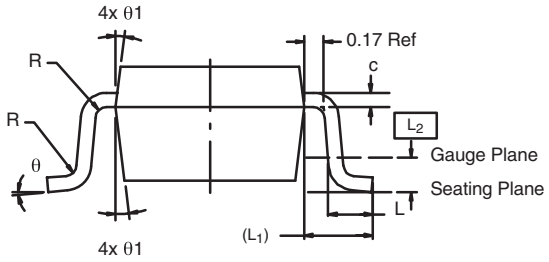


5-LEAD TSOP



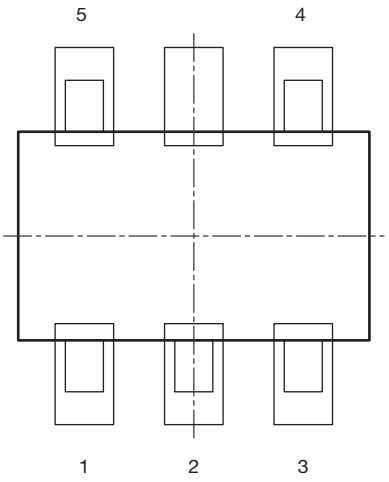
6-LEAD TSOP



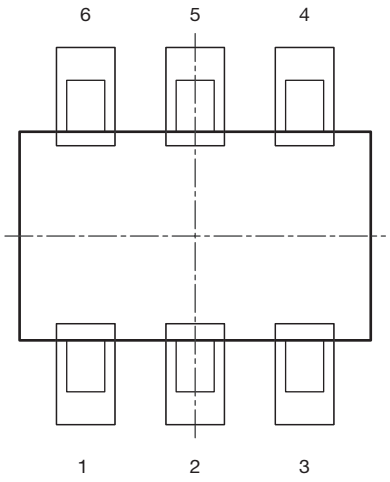


Dim	MILLIMETERS			INCHES		
	Min	Nom	Max	Min	Nom	Max
A	0.91	-	1.10	0.036	-	0.043
A_1	0.01	-	0.10	0.0004	-	0.004
A_2	0.90	-	1.00	0.035	0.038	0.039
b	0.30	0.32	0.45	0.012	0.013	0.018
c	0.10	0.15	0.20	0.004	0.006	0.008
D	2.95	3.05	3.10	0.116	0.120	0.122
E	2.70	2.85	2.98	0.106	0.112	0.117
E_1	1.55	1.65	1.70	0.061	0.065	0.067
e	0.95 BSC			0.0374 BSC		
e_1	1.80	1.90	2.00	0.071	0.075	0.079
L	0.32	-	0.50	0.012	-	0.020
L_1	0.60 Ref			0.024 Ref		
L_2	0.25 BSC			0.010 BSC		
R	0.10	-	-	0.004	-	-
θ	0°	4°	8°	0°	4°	8°
θ_1	7° Nom			7° Nom		
ECN: C-06593-Rev. I, 18-Dec-06 DWG: 5540						

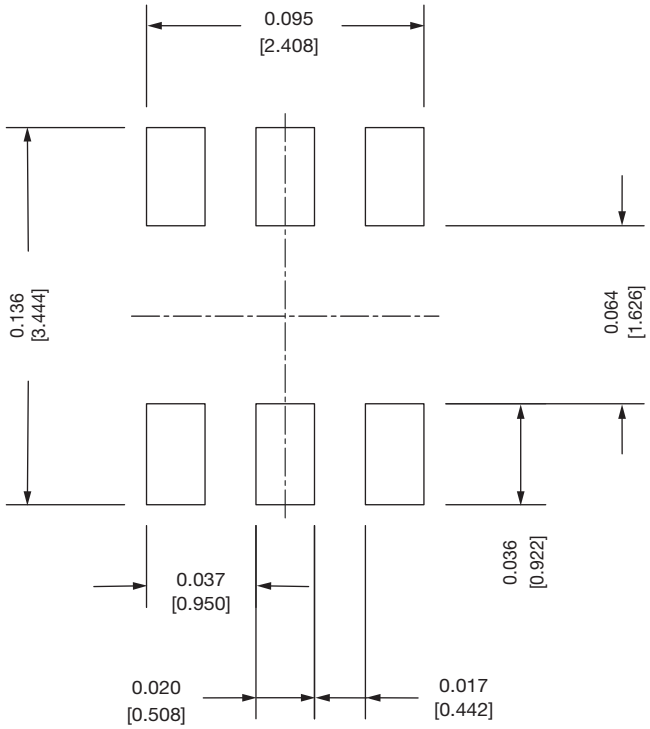
Recommended Land Pattern For TSOP-5L / TSOP-6L



TSOP 5L



TSOP 6L



Note

- All dimensions are in inches (millimeter)

ECN: C22-0860-Rev. B, 24-Oct-2022 DWG: 3010

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